# INTEGRATED CIRCUITS



Product specification Supersedes data of January 1994 File under Integrated Circuits, IC01



### SAA6579

### FEATURES

- Anti-aliasing filter (2nd order)
- Integrated 57 kHz band-pass filter (8th order)
- Reconstruction filter (2nd order)
- · Clocked comparator with automatic offset compensation
- 57 kHz carrier regeneration
- Synchronous demodulator for 57 kHz modulated RDS signals
- Selectable 4.332/8.664 MHz crystal oscillator with variable dividers
- Clock regeneration with lock on biphase data rate
- Biphase symbol decoder with integrate and dump functions
- Differential decoder
- Signal quality detector
- Subcarrier output.

### QUICK REFERENCE DATA

### **GENERAL DESCRIPTION**

The integrated CMOS circuit SAA6579 is an RDS demodulator. It recovers the additional inaudible RDS information which is transmitted by FM radio broadcasting.

The data signal RDDA and the clock signal RDCL are provided as outputs for further processing by a suitable decoder (microcomputer).

The operational functions of the device are in accordance with the "CENELEC EN 50067".

| SYMBOL              | PARAMETER  |  | TYP. | MAX. | UNIT |
|---------------------|--|--|------|------|------|
| V <sub>DDA</sub>    | analog supply voltage (pin 5)                                  |  | 5.0  | 5.5  | V    |
| V <sub>DDD</sub>    | digital supply voltage (pin 12)                                |  | 5.0  | 5.5  | V    |
| I <sub>tot</sub>    | total supply current   |  | 6    | -    | mA   |
| V <sub>i(rms)</sub> | RDS input amplitude (RMS value; pin 4)                         |  | -    | -    | mV   |
| V <sub>OH</sub>     | HIGH level output voltage for signals RDDA, RDCL, QUAL and T57 |  | -    | -    | V    |
| V <sub>OL</sub>     | LOW level output voltage for signals RDDA, RDCL, QUAL and T57  |  | -    | 0.4  | V    |
| T <sub>amb</sub>    | operating ambient temperature                                  |  | -    | +85  | °C   |

### **ORDERING INFORMATION**

| TYPE     | PACKAGE |   |          |  |  |  |
|----------|---------|---|----------|--|--|--|
| NUMBER   | NAME    | DESCRIPTION   | VERSION  |  |  |  |
| SAA6579  | DIP16   | plastic dual in-line package; 16 leads (300 mil); long body | SOT38-1  |  |  |  |
| SAA6579T | SO16    | plastic small outline package; 16 leads; body width 7.5 mm  | SOT162-1 |  |  |  |

## Radio Data System (RDS) demodulator

### **BLOCK DIAGRAM**



## Radio Data System (RDS) demodulator

### PINNING

| SYMBOL           | PIN | DESCRIPTION                                     |  |  |
|------------------|-----|---|--|--|
| QUAL             | 1   | quality indication output                       |  |  |
| RDDA             | 2   | RDS data output                                 |  |  |
| V <sub>ref</sub> | 3   | reference voltage output (0.5V <sub>DDA</sub> ) |  |  |
| MUX              | 4   | multiplex signal input                          |  |  |
| V <sub>DDA</sub> | 5   | +5 V supply voltage for analog part             |  |  |
| V <sub>SSA</sub> | 6   | ground for analog part (0 V)                    |  |  |
| CIN              | 7   | subcarrier input to comparator                  |  |  |
| SCOUT            | 8   | subcarrier output of reconstruction filter      |  |  |
| MODE             | 9   | oscillator mode/test control input              |  |  |
| TEST             | 10  | test enable input                               |  |  |
| V <sub>SSD</sub> | 11  | ground for digital part (0 V)                   |  |  |
| V <sub>DDD</sub> | 12  | +5 V supply voltage for digital part            |  |  |
| OSCI             | 13  | oscillator input                                |  |  |
| OSCO             | 14  | oscillator output                               |  |  |
| T57              | 15  | 57 kHz clock signal output                      |  |  |
| RDCL             | 16  | RDS clock output                                |  |  |



### SAA6579

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134); ground pins 6 and 11 connected together.

| SYMBOL           | PARAMETER                                  | CONDITIONS | MIN.  | MAX.            | UNIT |
|------------------|--|------------|-------|-----------------|------|
| V <sub>DDA</sub> | analog supply voltage (pin 5)              |            | 0     | 6               | V    |
| V <sub>DDD</sub> | digital supply voltage (pin 12)            |            | 0     | 6               | V    |
| V <sub>n</sub>   | voltage on all pins; grounds excluded      |            | -0.5  | $V_{DDX} + 0.5$ | V    |
| T <sub>stg</sub> | storage temperature                        |            | -40   | +150            | °C   |
| T <sub>amb</sub> | operating ambient temperature              |            | -40   | +85             | °C   |
| V <sub>es</sub>  | electrostatic handling for all pins except | note 1     | ±300  | -               | V    |
|                  | pins 9 and 10                              | note 2     | +1500 | -3000           | V    |

#### Notes

- 1. Equivalent to discharging a 200 pF capacitor via a 0  $\Omega$  series resistor.
- 2. Equivalent to discharging a 100 pF capacitor via a 1.5 k $\Omega$  series resistor.

### FUNCTIONAL DESCRIPTION

The SAA6579 is a demodulator circuit for RDS applications. It contains a 57 kHz bandpass filter and a digital demodulator to regenerate the RDS data stream out of the multiplex signal (MPX).

#### Filter part

The MUX signal is band-limited by a second-order anti-aliasing-filter and fed through a 57 kHz band-pass filter (8th order band-pass filter with 3 kHz bandwidth) to separate the RDS signals. This filter uses switched capacitor technique and is clocked by a clock frequency of 541.5 kHz derived from the 4.332/8.664 MHz crystal oscillator. Then the signal is fed to the reconstruction filter to smooth the sampled and filtered RDS signal before it is output on pin 8. The signal is AC-coupled to the comparator (pin 7). The comparator is clocked with a frequency of 228 kHz (synchronized by the 57 kHz of the demodulator).

### **Digital part**

The synchronous demodulator (Costas loop circuit) with carrier regeneration demodulates the internal coupled, digitized signal. The suppressed carrier is recovered from the two sidebands (Costas loop). The demodulated signal is low-pass-filtered in such a way that the overall pulse shape (transmitter and receiver) approaches a cosinusoidal form in conjunction with the following Integrate and dump circuit.

The data-spectrum shaping is split into two equal parts and handled in the transmitter and in the receiver. Ideally, the data filtering should be equal in both of these parts. The overall data-channel-spectrum shaping of the transmitter and the receiver is approximately 100% roll-off.

The Integrate and dump circuit performs an integration over a clock period. This results in a demodulated and valid RDS signal in form of biphase symbols being output from the integrate and dump circuit. The final stages of RDS data processing are the biphase symbol decoding and the differential decoding. After synchronization by data clock RDCL (pin 16) data appears on the RDDA output (pin 2). The output of the biphase symbol decoder is evaluated by a special circuit to provide an indication of good data (QUAL = HIGH) or corrupt data (QUAL = LOW).

### Timing

Fixed and variable dividers are applied to the 4.332/8.664 MHz crystal oscillator to generate the 1.1875 kHz RDS clock RDCL, which is synchronized by the incoming data. Which ever clock edge is considered (positive or negative going edge) the data will remain valid for 399  $\mu$ s after the clock transition. The timing of data change is 4  $\mu$ s before a clock change. Which clock transition (positive or negative going clock) the data change occurs in, depends on the lock conditions and is arbitrary (bit slip).

During poor reception it is possible that faults in phase occur, then the clock signal stays uninterrupted, and data is constant for 1.5 clock periods. Normally, faults in phase do not occur on a cyclic basis. If however, faults in phase occur in this way, the minimum spacing between two possible faults in phase depends on the data being transmitted. The minimum spacing cannot be less than 16 clock periods. The quality bit changes only at the time of a data change.

## SAA6579

### CHARACTERISTICS

 $V_{DDA} = V_{DDD} = 5 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}$  and measurements taken in Fig.1; unless otherwise specified.

| SYMBOL                    | PARAMETER                           | CONDITIONS   | MIN. | TYP. | MAX. | UNIT |  |  |
|---------------------------|-------------------------------------|--|------|------|------|------|--|--|
| V <sub>DDA</sub>          | analog supply voltage (pin 5)       |  | 3.6  | 5.0  | 5.5  | V    |  |  |
| V <sub>DDD</sub>          | digital supply voltage (pin 12)     |  | 3.6  | 5.0  | 5.5  | V    |  |  |
| I <sub>tot</sub>          | total supply current                | I <sub>5</sub> + I <sub>12</sub>   | -    | 6    | -    | mA   |  |  |
| V <sub>ref</sub>          | reference voltage (pin 3)           | $V_{DDA} = 5 V$  | -    | 2.5  | -    | V    |  |  |
| MPX input                 | (signal before the capacitor on pin | 4)   |      |      |      |      |  |  |
| V <sub>i MPX(rms)</sub>   | RDS amplitude (RMS value)           | $\Delta f = \pm 1.2 \text{ kHz RDS};$<br>$\Delta f = \pm 3.5 \text{ kHz ARI}; \text{ see Fig.5}$ | 1    | -    | -    | mV   |  |  |
| V <sub>i MPX(p-p)</sub>   | maximum input signal capability     | f = 57 ±2 kHz  | 200  | -    | -    | mV   |  |  |
|                           | (peak-to-peak value)                | f < 50 kHz   | 1.4  | -    | -    | V    |  |  |
|                           |                                     | f < 15 kHz   | 2.8  | -    | -    | V    |  |  |
|                           |                                     | f > 70 kHz   | 3.5  | -    | -    | V    |  |  |
| R <sub>4-6</sub>          | input resistance                    | f = 0 to 100 kHz   | 40   | -    | -    | kΩ   |  |  |
| G <sub>8-4</sub>          | signal gain                         | f = 57 kHz   | 17   | 20   | 23   | dB   |  |  |
| 57 kHz ban                | d-pass filter                       |  | ·    |      |      |      |  |  |
| f <sub>c</sub>            | centre frequency                    | T <sub>amb</sub> = -40 to +85 °C   | 56.5 | 57.0 | 57.5 | kHz  |  |  |
| В                         | -3 dB bandwidth                     |  | 2.5  | 3.0  | 3.5  | kHz  |  |  |
| G                         | stop band gain                      | $\Delta f = \pm 7 \text{ kHz}$   | 31   | -    | -    | dB   |  |  |
|                           |                                     | f < 45 kHz   | 40   | -    | -    | dB   |  |  |
|                           |                                     | f < 20 kHz   | 50   | -    | -    | dB   |  |  |
|                           |                                     | f > 70 kHz   | 40   | -    | -    | dB   |  |  |
| R <sub>0(8)</sub>         | output resistance (pin 8)           | f = 57 kHz   | -    | 26   | -    | Ω    |  |  |
| Comparato                 | Comparator input (pin 7)            |  |      |      |      |      |  |  |
| V <sub>i(rms)</sub>       | minimum input level (RMS value)     | f = 57 kHz   | -    | 1    | 10   | mV   |  |  |
| R <sub>i</sub>            | input resistance                    |  | 70   | 110  | 150  | kΩ   |  |  |
| Oscillator input (pin 13) |                                     |  |      |      |      |      |  |  |
| V <sub>IH</sub>           | HIGH level input voltage            | V <sub>DDD</sub> = 5.0 V   | 4.0  | _    | -    | V    |  |  |
| V <sub>IL</sub>           | LOW level input voltage             | V <sub>DDD</sub> = 5.0 V   | -    | -    | 1.0  | V    |  |  |
| lı –                      | input current                       | V <sub>DDD</sub> = 5.5 V   | -    | -    | ±1   | μA   |  |  |

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| SYMBOL  | PARAMETER                              | CONDITIONS  | MIN. | TYP.   | MAX. | UNIT             |  |
|---|--|---|------|--------|------|------------------|--|
| Digital demodulator and outputs QUAL, RDDA, T57, OSCO and RDCL (pins 1, 2, 14, 15 and 16) |  |   |      |        |      |                  |  |
| V <sub>OH</sub>   | HIGH level output voltage              | $I_Q = -20 \ \mu A; \ V_{DDD} = 4.5 \ V$          | 4.4  | -      | -    | V                |  |
| V <sub>OL</sub>   | LOW level output voltage               | I <sub>Q</sub> = 3.2 mA; V <sub>DDD</sub> = 5.5 V | -    | -      | 0.4  | V                |  |
| f <sub>RDCL</sub>   | nominal clock frequency RDCL           |   | -    | 1187.5 | -    | Hz               |  |
| $\Delta t_{RDCL}$   | jitter of RDCL                         |   | -    | -      | 18   | μs               |  |
| f <sub>T57</sub>  | nominal subcarrier frequency T57       | note 1  | -    | 57.0   | -    | kHz              |  |
| I <sub>O</sub>  | output current OSCO (pin 14)           | V <sub>DDD</sub> = 4.5 V; V <sub>14</sub> = 0.4 V | 1.5  | -      | -    | mA               |  |
|   |  | V <sub>DDD</sub> = 4.5 V; V <sub>14</sub> = 4.1 V | -1.6 | -      | -    | mA               |  |
|   | output current QUAL, RDDA, T57,        | V <sub>DDD</sub> = 4.5 V; V <sub>14</sub> = 0.4 V | 5.9  | -      | -    | mA               |  |
|   | RDCL (pins 1, 2, 15 and 16)            | V <sub>DDD</sub> = 4.5 V; V <sub>14</sub> = 4.1 V | -5.3 | -      | -    | mA               |  |
| 4.332 MHz   | crystal parameters                     |   |      |        |      |                  |  |
| f <sub>0</sub>  | XTAL frequency                         |   | -    | 4.332  | -    | MHz              |  |
| $\Delta f_{max}$  | maximum permitted tolerance            |   | -    | ±50    | -    | 10 <sup>-6</sup> |  |
| $\Delta f_{o}$  | adjustment tolerance of f <sub>0</sub> | T <sub>amb</sub> = 25 °C                          | -    | -      | ±20  | 10 <sup>-6</sup> |  |
|   |  | $T_{amb} = -40$ to +85 °C                         | -    | -      | ±25  | 10 <sup>-6</sup> |  |
| CL  | load capacitance                       |   | -    | 30     | -    | pF               |  |
| R <sub>xtal</sub>   | resonance resistance                   |   | -    | -      | 60   | Ω                |  |
| 8.664 MHz crystal parameters  |  |   |      |        |      |                  |  |
| f <sub>0</sub>  | XTAL frequency                         |   | -    | 8.664  | -    | MHz              |  |
| $\Delta f_{max}$  | maximum permitted tolerance            |   | -    | ±50    | -    | 10 <sup>-6</sup> |  |
| $\Delta f_{o}$  | adjustment tolerance of f <sub>0</sub> | T <sub>amb</sub> = 25 °C                          | -    | -      | ±30  | 10 <sup>-6</sup> |  |
|   |  | $T_{amb} = -40$ to +85 °C                         | -    | -      | ±30  | 10-6             |  |
| CL  | load capacitance                       |   | -    | 30     | -    | pF               |  |
| R <sub>xtal</sub>   | resonance resistance                   |   | -    | -      | 60   | Ω                |  |

Note

1. The signal T57 has a phase lead of 123° (±180°) relative to the ARI carrier at output SCOUT.

# Radio Data System (RDS) demodulator





1997 Feb 24

### PACKAGE OUTLINES

### DIP16: plastic dual in-line package; 16 leads (300 mil); long body



### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE |        | REFERENCES EURO |      |  | EUROPEAN   |                                  |
|---------|--------|-----------------|------|--|------------|----------------------------------|
| VERSION | IEC    | JEDEC           | EIAJ |  | PROJECTION |                                  |
| SOT38-1 | 050G09 | MO-001AE        |      |  |            | <del>-92-10-02</del><br>95-01-19 |

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SOT38-1

### Radio Data System (RDS) demodulator

#### SO16: plastic small outline package; 16 leads; body width 7.5 mm SOT162-1 А D Х = v M A y Q A2 4 (A<sub>3</sub>) A<sub>.1</sub> pin 1 index Г detail X е 10 mm 0 5 scale DIMENSIONS (inch dimensions are derived from the original mm dimensions) Α z<sup>(1)</sup> UNIT D<sup>(1)</sup> E<sup>(1)</sup> Q θ ${\rm H}_{\rm E}$ L A<sub>1</sub> $A_2$ $A_3$ bp С е Lp v w у max. 10.65 0.30 2.45 0.49 0.32 0.9 10.5 7.6 1.1 1.1 2.65 mm 0.25 1.27 1.4 0.25 0.25 0.1 0.10 2.25 0.36 0.23 10.1 7.4 10.00 0.4 1.0 0.4 8<sup>0</sup> 0° 0.012 0.004 0.043 0.016 0.096 0.42 0.035 0.019 0.013 0.41 0.30 0.043 inches 0.10 0.01 0.050 0.055 0.01 0.01 0.004 0.089 0.014 0.009 0.40 0.29 0.39 0.039 0.016 Note 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included. REFERENCES EUROPEAN OUTLINE ISSUE DATE VERSION PROJECTION IEC EIAJ JEDEC 92-11-17 SOT162-1 075E03 MS-013AA 95-01-24

### SAA6579

### SOLDERING

### Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "IC Package Databook" (order code 9398 652 90011).

#### DIP

#### SOLDERING BY DIPPING OR BY WAVE

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ( $T_{stg\,max}$ ). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

#### REPAIRING SOLDERED JOINTS

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

### SO

#### **REFLOW SOLDERING**

Reflow soldering techniques are suitable for all SO packages.

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Several techniques exist for reflowing; for example, thermal conduction by heated belt. Dwell times vary between 50 and 300 seconds depending on heating method. Typical reflow temperatures range from 215 to 250 °C.

Preheating is necessary to dry the paste and evaporate the binding agent. Preheating duration: 45 minutes at 45 °C.

#### WAVE SOLDERING

Wave soldering techniques can be used for all SO packages if the following conditions are observed:

- A double-wave (a turbulent wave with high upward pressure followed by a smooth laminar wave) soldering technique should be used.
- The longitudinal axis of the package footprint must be parallel to the solder flow.
- The package footprint must incorporate solder thieves at the downstream end.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Maximum permissible solder temperature is 260 °C, and maximum duration of package immersion in solder is 10 seconds, if cooled to less than 150 °C within 6 seconds. Typical dwell time is 4 seconds at 250 °C.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### REPAIRING SOLDERED JOINTS

Fix the component by first soldering two diagonallyopposite end leads. Use only a low voltage soldering iron (less than 24 V) applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C. When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 °C.

### SAA6579

### DEFINITIONS

| Data sheet status   |  |  |  |  |
|---|--|--|--|--|
| Objective specification   | bjective specification This data sheet contains target or goal specifications for product development. |  |  |  |
| Preliminary specification   | This data sheet contains preliminary data; supplementary data may be published later.                  |  |  |  |
| Product specification   | This data sheet contains final product specifications.   |  |  |  |
| Limiting values   |  |  |  |  |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |  |  |  |  |
| Application information   |  |  |  |  |

Where application information is given, it is advisory and does not form part of the specification.

### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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